

20V P-Channel Enhancement Mode MOSFET - ESD Protected

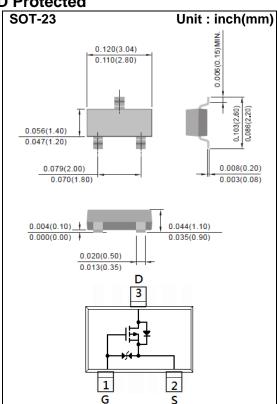
Voltage -20 V Current -4.3A

Features

- RDS(ON) , VGS@-4.5V, ID@-4.3A<50mΩ
- RDS(ON) , VGS@-2.5V, ID@-4.0A<58mΩ
- RDS(ON), VGS@-1.8V, ID@-2.4A<73m Ω
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case: SOT-23 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0084 grams
- Marking: A5AE



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-20	V
Gate-Source Voltage		V _G s	<u>+</u> 8	V
Continuous Drain Current		I _D	-4.3	Α
Pulsed Drain Current		I _{DM}	-17.2	А
Power Dissipation	T _a =25°C	_	1.25	W
	Derate above 25°C	P₀	10	mW/°C
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C
Typical Thermal Resistance				
- Junction to Ambient (Note 3)		Reja	100	°C/W



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-20	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =-250uA	-0.4	-0.55	-1.0	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-4.3A	-	42	50	mΩ	
		V _{GS} =-2.5V, I _D =-4.0A	-	49	58		
		V _{GS} =-1.8V, I _D =-2.4A	-	59	73		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V	-	-0.01	-1	uA	
Gate-Source Leakage Current	Igss	V _{GS} = <u>+</u> 8V, V _{DS} =0V	-	<u>+</u> 6	<u>+</u> 10	uA	
Dynamic (Note 5)							
Total Gate Charge	Q_g	\/ 40\/ L 40A	-	24	-	nC	
Gate-Source Charge	Q_gs	V _{DS} =-10V, I _D =-4.3A, V _{GS} =-4.5V (Note 1,2)	-	1.5	-		
Gate-Drain Charge	Q_{gd}	VGS=-4.5V (1666 1,2)	-	2.5	-		
Input Capacitance	Ciss	10 10 1	-	907	-	pF	
Output Capacitance	Coss	V _{DS} =-10V, V _{GS} =0V,	-	90	-		
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	70	-		
Turn-On Delay Time	td _(on)	10)/ 1 10	-	45	-		
Turn-On Rise Time	tr	V _{DD} =-10V, I _D =-4.3A, V _{GS} =-4.5V,	-	79	-	ns	
Turn-Off Delay Time	td _(off)	$R_{G}=6\Omega$ (Note 1,2)	-	193	-		
Turn-Off Fall Time	tf	NG=012 (********)	-	826	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	-1.5	А	
Diode Forward Voltage	V _{SD}	I _S =-1.0A, V _{GS} =0V	-	0.76	-1.2	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper
- 4. The maximum current rating is package limited
- 5. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

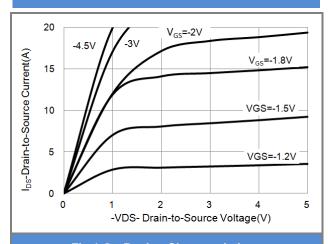


Fig.1 On-Region Characteristics

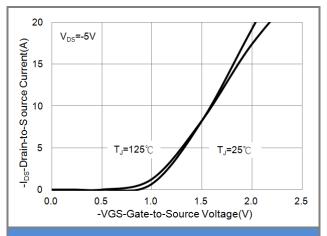


Fig.2 Transfer Characteristics

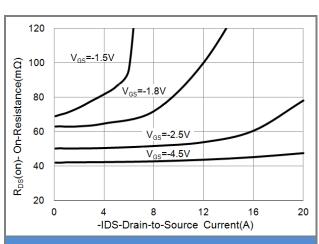


Fig.3 On-Resistance vs. Drain Current

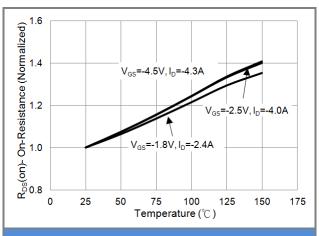


Fig.4 On-Resistance vs. Junction temperature

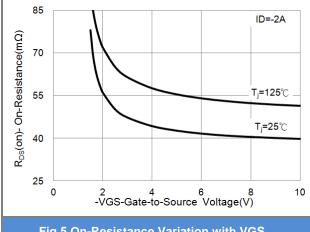


Fig.5 On-Resistance Variation with VGS.

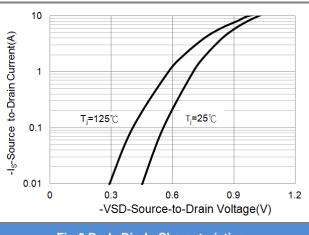


Fig.6 Body Diode Characteristics



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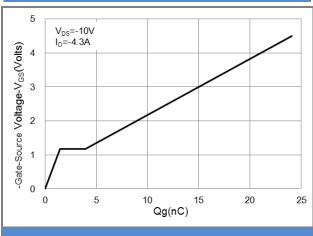


Fig.7 Gate-Charge Characteristics

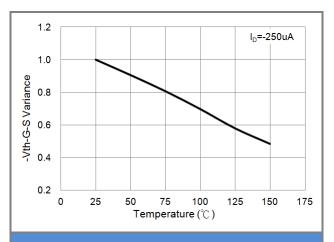


Fig.8 Threshold Voltage Variation with Temperature.

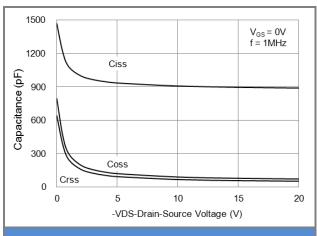


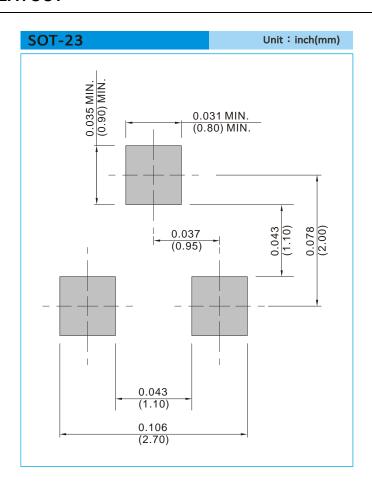
Fig.9 Capacitance vs. Drain-Source Voltage.



Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJA3415AE	SOT-23	3K pcs / 7" reel	A5AE	

MOUNTING PAD LAYOUT





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